74LVCE1G07

SINGLE BUFFER/DRIVER WITH OPEN DRAIN OUTPUT

NEW PRODUCT

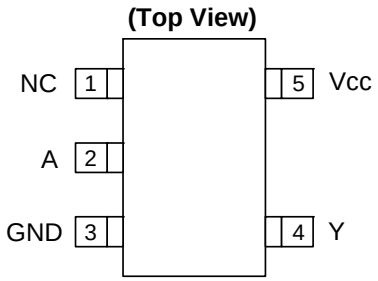
Description

The 74LVCE1G07 is a single inverter gate with an open drain output. The device is designed for operation with a power supply range of 4V to 5.5V. The input is tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down. The open-drain output can be connected to other open drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32 mA.

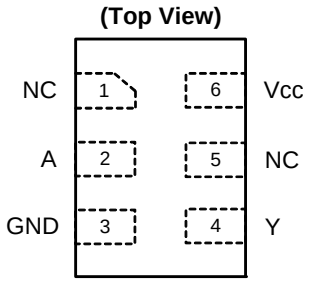
Features

- Wide Supply Voltage Range from 1.65 to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- I_{OFF} Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
  - Exceeds 200-V Machine Model (A115-A)
  - Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments



SOT25 / SOT353



DFN1410 (Note 2)

Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as.
  - o PCs, networking, notebooks, netbooks, PDAs
  - o Computer peripherals, hard drives, CD/DVD ROM
  - o TV, DVD, DVR, set top box
  - o Cell Phones, Personal Navigation / GPS
  - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

2. Pin 2 and pin 5 of the DFN1410 package are internally connected.

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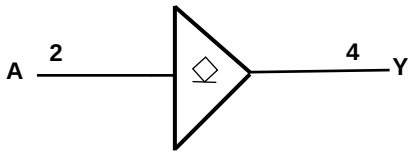
Pin Descriptions

Pin Name	Description
NC	No connection
A	Data Input
GND	Ground
Y	Data Output Open Drain
Vcc	Supply Voltage

Logic Diagram



Function Table

Inputs	Output
A	**Y**
H	Z
L	L

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Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to 6.5	V
V_I	Input Voltage Range	-0.5 to 6.5	V
V_o	Voltage applied to output in high impedance or I_{OFF} state	-0.5 to 6.5	V
V_o	Voltage applied to output in high or low state	-0.3 to V_{CC} +0.5	V
I_{IK}	Input Clamp Current V_I<0	-50	mA
I_{OK}	Output Clamp Current	-50	mA
I_O	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
T_J	Operating Junction Temperature	-40 to 150	°C
T_{STG}	Storage Temperature	-65 to 150	°C

Notes: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

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Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Operating Voltage	Operating	1.4	5.5	V
		Data retention only	1.2		V
V_{IH}	High-level Input Voltage	V_{CC} = 1.4 V to 1.95 V	0.65 X V_{CC}		V
		V_{CC} = 2.3 V to 2.7 V	1.7		
		V_{CC} = 3 V to 3.6 V	2		
		V_{CC} = 4.5 V to 5.5 V	0.7 X V_{CC}		
V_{IL}	Low-level input voltage	V_{CC} = 1.4 V to 1.95 V		0.35 X V_{CC}	V
		V_{CC} = 2.3 V to 2.7 V		0.7	
		V_{CC} = 3 V to 3.6 V		0.8	
		V_{CC} = 4.5 V to 5.5 V		0.3 X V_{CC}	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage		0	V_{CC}	V
I_{OL}	Low-level output current	Vcc=1.4 V		3	mA
		V_{CC} = 1.65 V		4	
		V_{CC} = 2.3 V		8	
		V_{CC} = 3 V		16	
				24	
		V_{CC} = 4.5 V		32	
Δt/ΔV	Input transition rise or fall rate	V_{CC} = 1.4 V to 3.0 V		20	ns/V
		V_{CC} = 3.3 V ± 0.3 V		10	
		V_{CC} = 5 V ± 0.5 V		5	
T_A	Operating free-air temperature		-40	85	ºC

Notes: 4. Unused inputs should be held at Vcc or Ground.

NEW PRODUCT

Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

Over recommended free-air temperature range (unless otherwise noted)

Symbol	Parameter	Test Conditions	Vcc	Min	Typ	Max	Unit
V_{OL}	Low Level Output Voltage	I_{OL} = 100 µA	1.4 V to 5.5 V			0.1	V
		I_{OL} = 3 mA	1.4 V			0.4	
		I_{OL} = 4 mA	1.65 V			0.45	
		I_{OL} = 8 mA	2.3 V			0.3	
		I_{OL} = 16 mA	3 V			0.4	
		I_{OL} = 24 mA				0.55	
		I_{OL} = 32 mA	4.5 V			0.55	
I_I	Input Current	V_I = 5.5 V or GND	0 to 5.5 V			± 5	µA
I_{OZ}	Z State Leakage Current	V_O = 5.5V	3.6 V			± 10	µA
I_{OFF}	Power Down Leakage Current	V_I or V_O = 5.5V	0 V			± 10	µA
I_{CC}	Supply Current	V_I = 5.5 V or GND I_O=0	1.4 V to 5.5 V			10	µA
ΔI_{CC}	Additional Supply Current	Input at V_{CC} –0.6 V	3 V to 5.5 V			500	µA
C_{Ii}	Input Capacitance	V_I = V_{CC} or GND	3.3V		4		pF
C_O	Output Capacitance	V_O= V_{CC} or GND	3.3V		5		pF
θ_{JA}	Thermal Resistance Junction-to-Case	SOT25	(Note 5)		204		ºC/W
		SOT353	(Note 5)		371		
		DFN1410	(Note 5)		430		
θ_{JC}	Thermal Resistance Junction-to-Case	SOT25	(Note 5)		52		ºC/W
		SOT353	(Note 5)		143		
		DFN1410	(Note 5)		190		

Notes: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

NEW PRODUCT

Switching Characteristics

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)	Vcc = 1.5 V ± 0.1V		Vcc = 1.8 V ± 0.15V		Vcc = 2.5 V ± 0.2V		Vcc = 3.3 V ± 0.3V		Vcc = 5 V ± 0.5V		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t_{pd}	A	Y	1.5	9.9	1	5.8	0.8	4.4	0.8	3.4	0.8	3.1	ns

Operating Characteristics

T_A = 25 ºC

Parameter		Test Conditions	Vcc = 1.5 V	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
			TYP	TYP	TYP	TYP	TYP	
C_{pd}	Power dissipation capacitance	f = 10 MHz	3	3	3	4	6	pF

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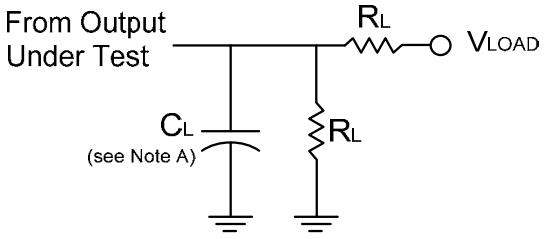
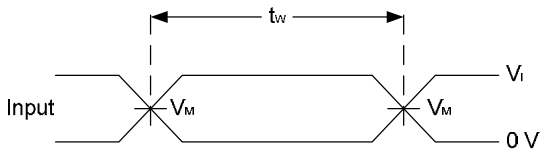
Parameter Measurement Information

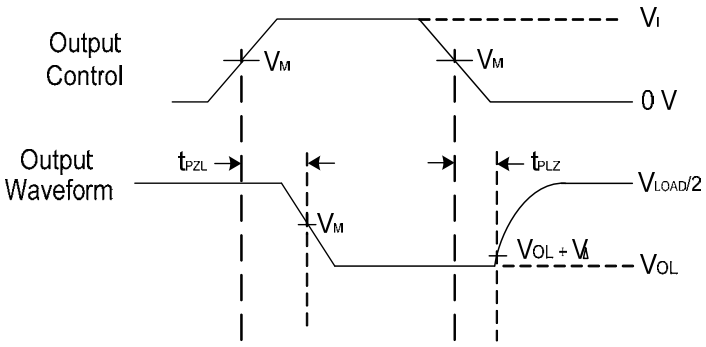


TEST	Condition
t_{PLZ} (see Notes D and E)	Vload
t_{PZL}(see Notes D and F)	Vload

Vcc	Inputs		V_M	V_{LOAD}	C_L	R_L	$V\Delta$
	V_I	t_r/t_f					
1.8V±0.15V	V_{CC}	≤2ns	$V_{CC}/2$	2 X V_{CC}	30pF	1KΩ	0.15V
2.5V±0.2V	V_{CC}	≤2ns	$V_{CC}/2$	2 X V_{CC}	30pF	500Ω	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
5V±0.5V	V_{CC}	≤2.5ns	$V_{CC}/2$	2 X V_{CC}	50pF	500Ω	0.3V



Voltage Waveform Pulse Duration



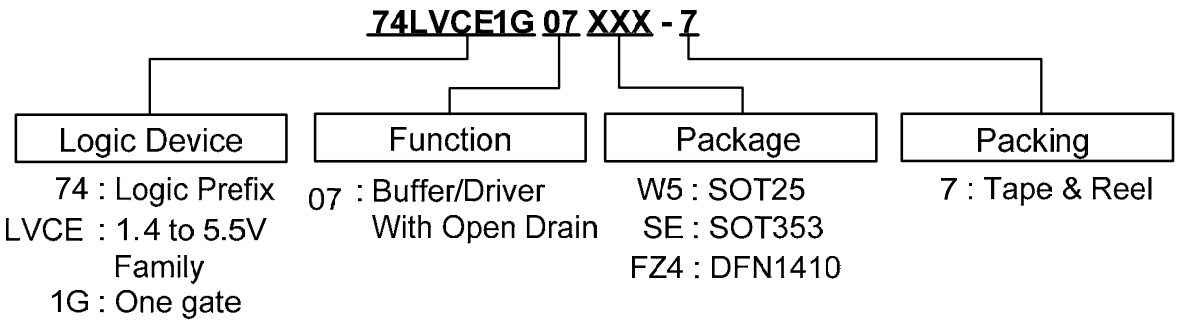
Voltage Waveform Propagation Delay Times

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
C. The inputs are measured one at a time with one transition per measurement.
D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD}
E. t_{PZL} is measured at V_M.
F. t_{PLZ} is measured at V_{OL} +V_Δ

NEW PRODUCT

Ordering Information



Device	Package Code	Packaging (Note 6)	7" Tape and Reel	
			Quantity	Part Number Suffix
74LVCE1G07W5-7	W5	SOT25	3000/Tape & Reel	-7
74LVCE1G07SE-7	SE	SOT353	3000/Tape & Reel	-7
74LVCE1G07FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7

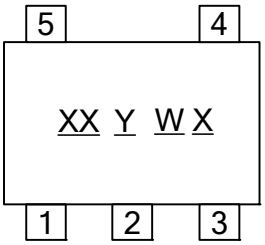
Notes: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

NEW PRODUCT

Marking Information

(1) SOT25 and SOT353

(Top View)

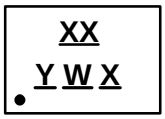


XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents 52 and 53 week
X : A~Z : Internal code

Part Number	Package	Identification Code
74LVCE1G07W5	SOT25	PN
74LVCE1G07SE	SOT353	PN

(3) DFN1410

(Top View)



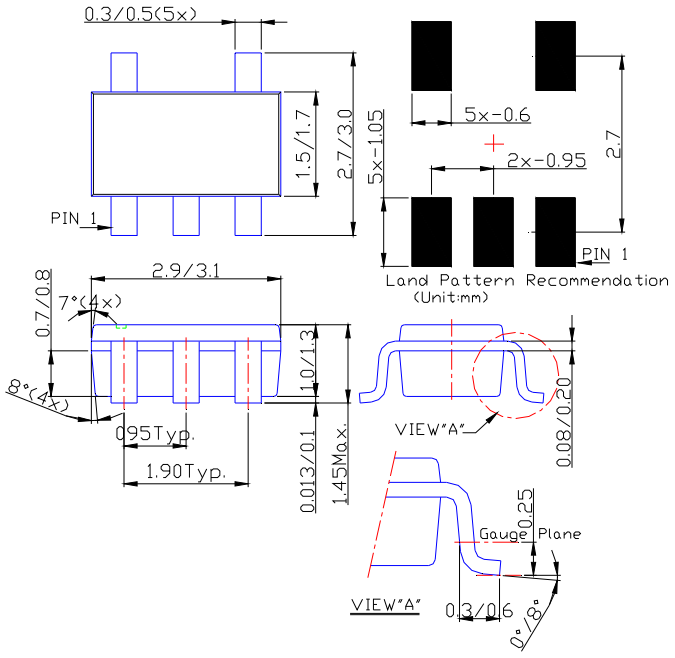
XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents 52 and 53 week
X : A~Z : Internal code

Part Number	Package	Identification Code
74LVCE1G07FZ4	DFN1410	PN

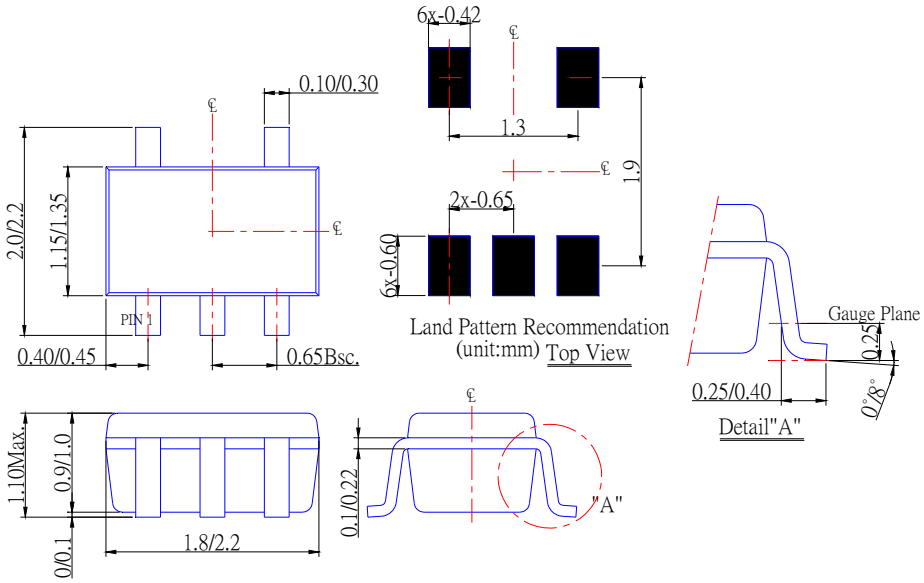
NEW PRODUCT

Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



(2) Package Type: SOT353



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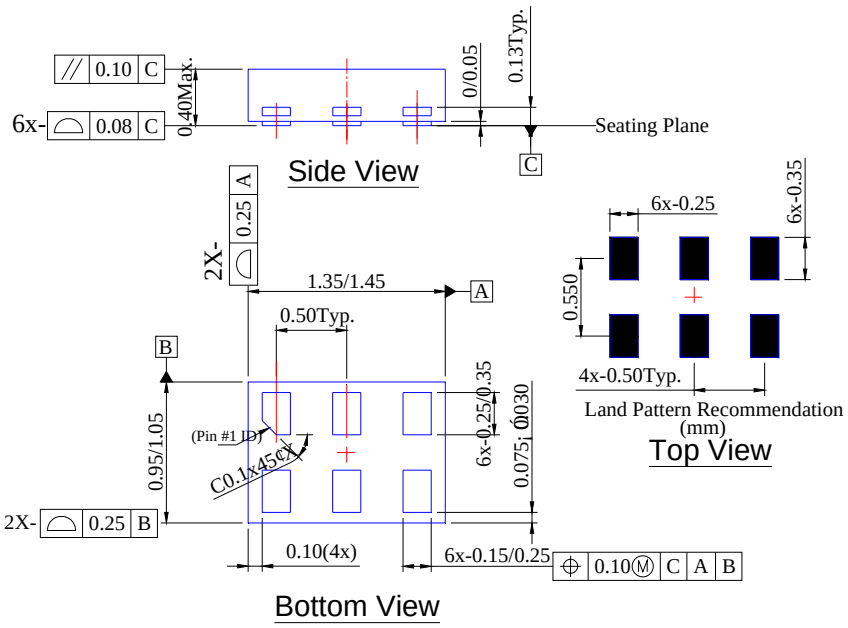
Package Outline Dimensions (Continued)

(3) Package Type: DFN1410



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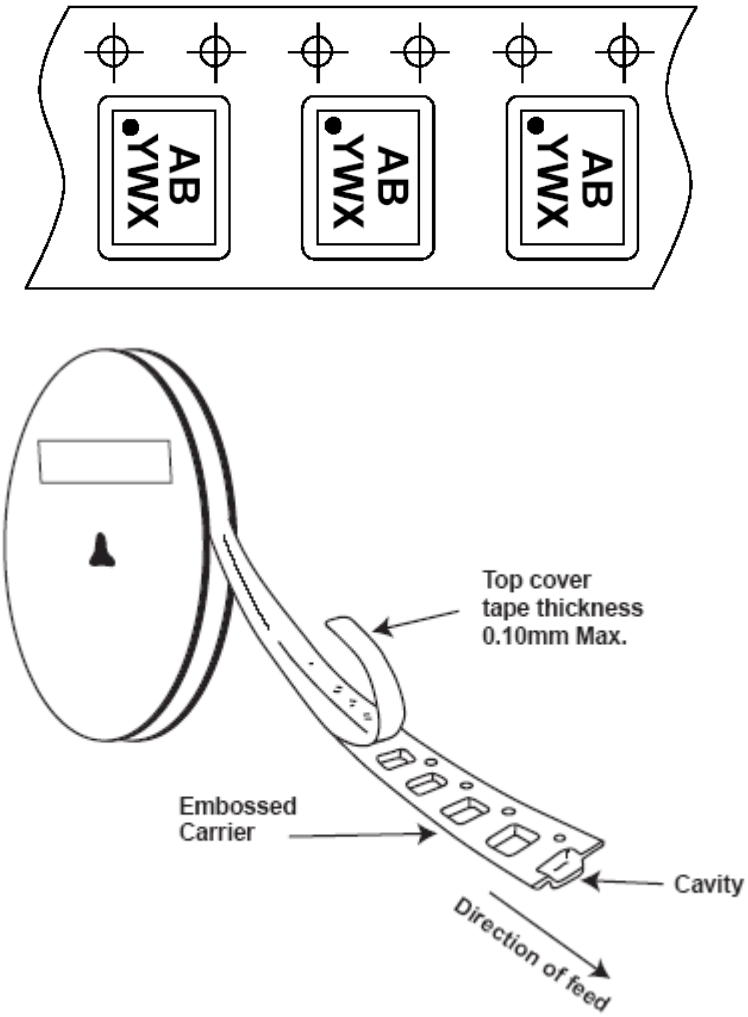
Taping Orientation (Note 7)

For DFN1410



Notes: 7. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf

NEW PRODUCT

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